MA4EX600L1-1225T



Silicon Double Balanced HMIC Mixer 1700 – 2500 MHz

Rev. V1

Features

- SOT-25 Low Cost Miniature Plastic Package
- 6.4 dB Typical Conversion Loss @ 5000 MHz
- + 3 to + 7 dBm LO Drive
- HMICTM Patented Process
- NO External Matching Required
- Double Balanced Passive Mixer
- Lead Free (RoHS Compliant) with 260 °C Reflow Capability
- 100 % Matte Tin Plating

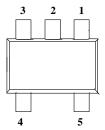
Description

M/A-COM's MA4EX600L1-1225T is a silicon monolithic 4.2 – 6.0GHz double balanced mixer in a low cost miniature surface mount SOT-25 package. The die uses M/A-COM's unique HMIC silicon/glass process to realize low loss passive elements while retaining the advantages of low barrier silicon Schottky diodes.

Applications

These mixers are well suited for high volume WLL and WLAN applications where small size and repeatability are required. Typical applications include frequency conversion, modulation, and demodulation in wireless receivers and transmitters.

SOT-25 Package Outline (Topview)



PIN Configuration

PIN	Function	PIN	Function	
1	RF	4	GND	
2	GND	5	IF	
3	LO	_	_	

Ordering Information

Model No.	Package	
MA4EX600L1-1225T	Tape and Reel	

Electrical Specifications @ +25°C

Parameter	Frequency Range	Test Conditions	Units	Min.	Тур.	Max.
Conversion Loss	5000 MHz	LO Drive = +5 dBm	dB	-	6.4	8.0
	4.2 - 6.0 GHz	RF = -10 dBm, IF = 60 MHz			6.8	9.5
L - R Isolation	5000 MHz	LO Drive = +5 dBm	dB	-	26	-
	4.2 - 6.0 GHz	LO DIIVE = +3 dBIII			25	
L - I Isolation	5000 MHz	LO Drive = +5 dBm	dB	-	24	-
	4.2 – 6.0 GHz	LO DIIVE = +3 dBIII			23	
R - I Isolation	5000 MHz	LO Drive = +5 dBm	dB	-	13	-
	4.2 - 6.0 GHz	RF Level = - 10 dBm			15	
RF VSWR	5000 MHz	LO Drive = +5 dBm	Ratio	-	1.18:1	-
	4.2 - 6.0 GHz	RF Level = - 10 dBm			1.67:1	
LO VSWR	5000 MHz	LO Drive = +5 dBm	Ratio	-	1.87:1	-
	4.2 - 6.0 GHz	LO DIIVE = +3 dBIII			1.89:1	
IF VSWR	10 - 2000 MHz	LO Drive = +5 dBm	Ratio	-	1.55:1	-
	10 - 2000 IVII IZ	IF Level = 0 dBm			1.55.1	
Input IP3	5000 MHz	LO Drive = +5 dBm	dBm	-	5.7	-
	4.2 - 6.0 GHz	RF = -10 dBm, IF = 60 MHz			7.6	
Input 1 dB	5000 MHz	LO Drive = +5 dBm	dBm	-	0.3	-
Compression Power	4.2 - 6.0 GHz	IF = 60 MHz			0.8	
IF 1 dB Bandwidth	DC - 2000 MHz	LO = 5000 MHz @+5dBm	MHz	0	-	2000

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China Tel: +86.21.2407.1588
Visit www.macomtech.com for additional data sheets and product information.

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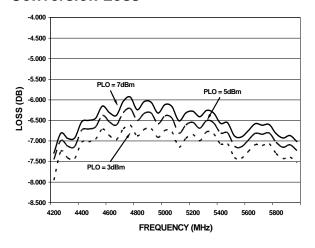


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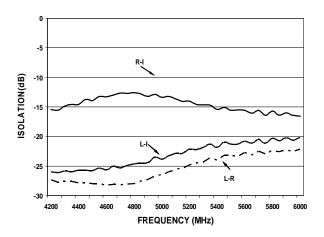
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Typical Performance Curves (LO Drive = + 5 dBm, RF = -10dBm, IF = 60MHz)

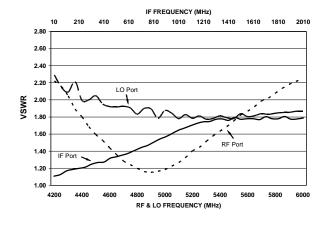
Conversion Loss



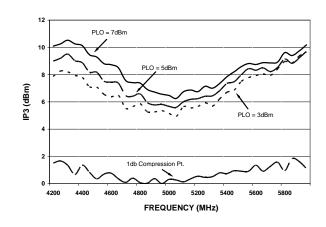
Isolation



VSWR



Input IP3 & 1dB Compression Power



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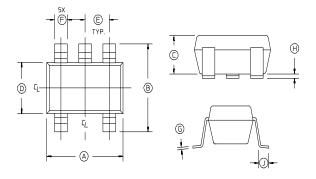


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Rev. V1

Case Style

SOT-25



Absolute Maximum Ratings 1

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Parameter	Maximum Ratings
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C
Incident LO Power	+20 dBm
Incident RF Power	+20 dBm
Soldering Temperature	+260°C max.

- 1. Exceeding these limits may cause permanent damage.
- * Please refer to application note M538 for surface mounting instructions.

SOT-25

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	.1103	.1181	2.80	3.10
В	.1023	.1181	2.6	3.00
С	0.0355	.0512	0.9	1.30
D	0.0591	.0669	1.5	1.70
E	.0374 REF.		0.95 REF.	
F	.0138	.0197	.35	.50
G	.0031	0.0079	.08	0.2
Н	.0002	.0059	.05	.15
J	.0138	.0216	.35	.55

- 1. Dimensions do not include mold flas, protrusion or gate burrs which shall not exceed 0.0098 in (.25mm) per side.
- 2. Leads Coplanarity should be 0.003 (0.08) max.

Schematic

